

**66095****MINIATURE LCC OPTOCOUPLER**
**OPTOELECTRONIC PRODUCTS  
DIVISION**
**Features:**

- Electrically similar to 4N47, 4N48, or 4N49
- Standard and screened versions available
- Hermetically sealed 4 pin LCC
- High-voltage electrical isolation...1kV rating

**Applications:**

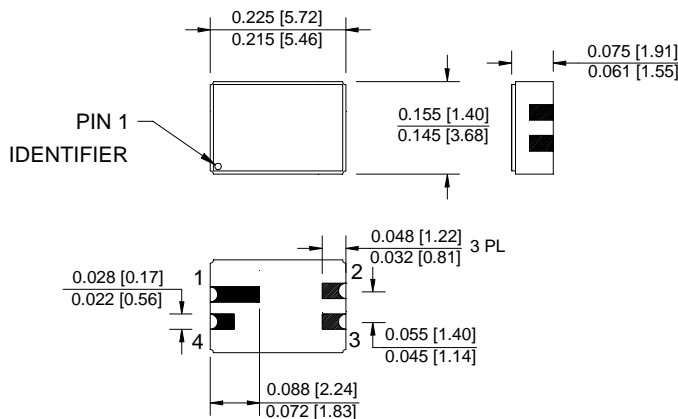
- High density surface mount circuits
- Ground loop isolation
- Feedback controls
- General purpose switching circuits

**DESCRIPTION**

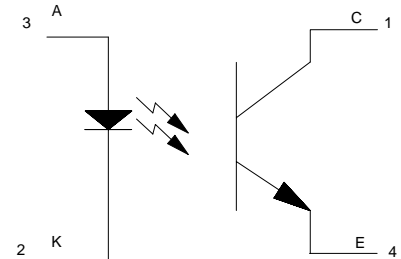
The **66095** series optocouplers consist of an infrared LED and a silicon phototransistor in a 4 pin hermetically sealed leadless chip carrier. The 66095 is electrically similar to the 4N47, 4N48, or 4N49 series optocouplers, and is available in standard and screened versions. The 66095 miniature LCC is ideal for surface mount applications where board space is limited.

**ABSOLUTE MAXIMUM RATINGS**

Input-to-Output Voltage .....	± 1 KV
Collector-Emitter Voltage .....	40 V
(This value applies with the input-diode current equal to zero)	
Input Diode Reverse Voltage .....	2 V
Input Diode Continuous Forward Current at (or below) 65°C Free-Air Temperature .....	40 mA
(Derate linearly to 125°C free-air temperature at the rate of 0.67 mA/°C)	
Continuous Collector Current.....	50 mA
Peak Diode Current....(This Value applies for $t_w \leq 1\mu s$ , PRR < 300 pps) .....	1A
Continuous Transistor Power Dissipation at (or below) 25°C Free-Air Temperature .....	300mW
(Derate linearly to 125°C free-air temperature at the rate of 3 mW/°C)	
Operating and Storage Free-Air Temperature Range.....	-55°C to +125°C
Lead Temperature 1.6mm (1/16 inch) from Case for 10 seconds .....	245°C

**Package Dimensions**

ALL DIMENSIONS ARE IN INCHES [MILLIMETERS]

**Schematic Diagram**

**ELECTRICAL CHARACTERISTICS**T<sub>A</sub> = 25°C unless otherwise specified.

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS	NOTE
Input Diode Static Reverse Current	I <sub>R</sub>			100	μA	V <sub>R</sub> = 2V	
Input Diode Static Forward Voltage	V <sub>F</sub>	1.3	1.5	1.7	V	I <sub>F</sub> = 10mA	
-55°C		1.3	1.5	1.7	V		
+25°C		1.3	1.5	1.7	V		
+100°C		1.3	1.5	1.7	V		

**OUTPUT TRANSISTOR**T<sub>A</sub> = 25°C unless otherwise specified.

Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	40			V	I <sub>C</sub> = 1mA, I <sub>F</sub> = 0	
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**COUPLED CHARACTERISTICS**T<sub>A</sub> = 25°C unless otherwise specified.

On State Collector Current	-XX1	I <sub>C(ON)</sub>	0.5		-	V <sub>CE</sub> = 5V, I <sub>F</sub> = 1mA		
T <sub>a</sub> = +25°C	-XX2		1		5			mA
	-XX3		2		10			
On State Collector Current	-XX1	I <sub>C(ON)</sub>	0.7			V <sub>CE</sub> = 5V, I <sub>F</sub> = 2mA		
T <sub>a</sub> = -55°C	-XX2		1.4					mA
	-XX3		2.8					
On State Collector Current	-XX1	I <sub>C(ON)</sub>	0.5			V <sub>CE</sub> = 5V, I <sub>F</sub> = 2mA	2	
T <sub>a</sub> = +100°C	-XX2		1.0					mA
	-XX3		2.0					
Off State Collector Current		I <sub>C(OFF)</sub>			100	V <sub>CE</sub> = 20V, I <sub>F</sub> = 0mA		
Off State Collector Current, T <sub>a</sub> = 100°C		I <sub>C(OFF)</sub>			100	V <sub>CE</sub> = 20V, I <sub>F</sub> = 0mA		
Collector-Emitter Saturation Voltage	-X01	V <sub>CE(SAT)</sub>			0.3	I <sub>F</sub> = 2mA, I <sub>C</sub> = 0.5mA I <sub>F</sub> = 2mA, I <sub>C</sub> = 1mA I <sub>F</sub> = 2mA, I <sub>C</sub> = 2mA		
	-X02	V <sub>CE(SAT)</sub>			0.3			V
	-X03	V <sub>CE(SAT)</sub>			0.3			
Input to Output Resistance		R <sub>IO</sub>	10 <sup>11</sup>			V <sub>IN-OUT</sub> = 1kV	1	
Input to Output Capacitance		C <sub>IO</sub>		2.5	5	F = 1MHz, V <sub>IN-OUT</sub> = 0	1	
Rise Time (Phototransistor Operation)	-XX1	t <sub>r</sub>		10	20	V <sub>CC</sub> = 10V, I <sub>C</sub> = 5mA, R <sub>L</sub> = 100Ω		
or	-XX2	or		10	25			μs
Fall Time	-XX3	t <sub>f</sub>		10	25			

**NOTES:**

- These parameters are measured between all phototransistor leads shorted together and with both input diode leads shorted together.
- This parameter must be measured using pulse techniques. t<sub>w</sub> = 100 μs, duty cycle ≤ 1%.

**RECOMMENDED OPERATING CONDITIONS:**

PARAMETER	SYMBOL	MIN	MAX	UNITS
Input Current, Low Level	I <sub>FL</sub>	0	100	μA
Input Current, High Level	I <sub>FH</sub>	1	2	mA
Supply Voltage	V <sub>CC</sub>	5.0	20	V
Operating Temperature	T <sub>A</sub>	-55	125	°C